

A study of 3D Silicon pixel sensors using ROC4sens read-out chip in a DESY test beam

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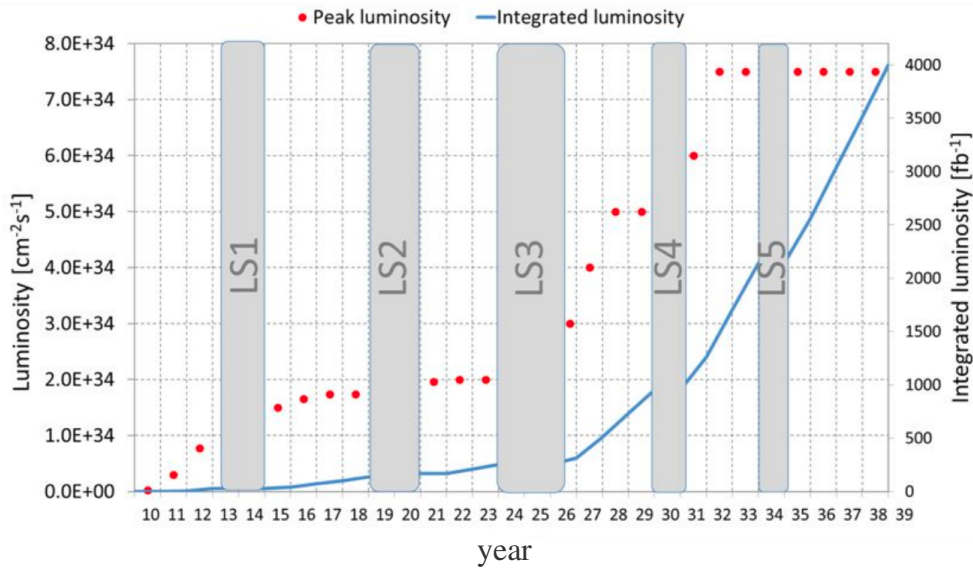
¹IFCA – ²CERN – ³CNM – ⁴DESY – ⁵Hamburg University



31st RD50 Workshop
Radiation hard semiconductor devices for very high luminosity colliders
CERN, 20-22 November 2017



Motivation: CMS Upgrade (HL-LHC)

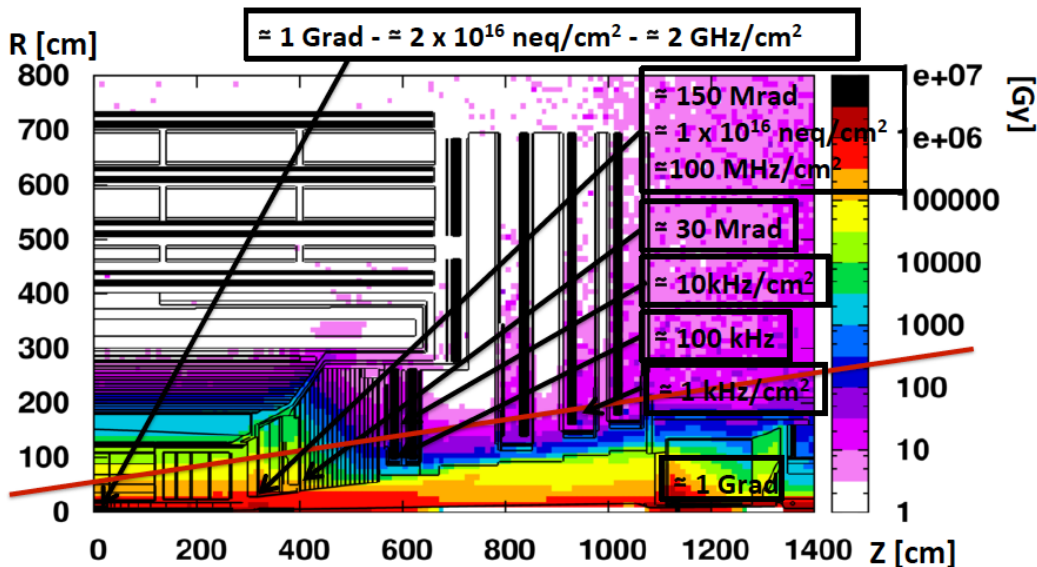


Pile-up ~ 200

Higher occupancy: Increases combinatorial complexity and rate of fake tracks. Increases amount of data to be read out in each bunch crossing.

Mitigation

High granularity detectors: needed to identify particles associated with the primary hard scatter collision vertex with high efficiency.



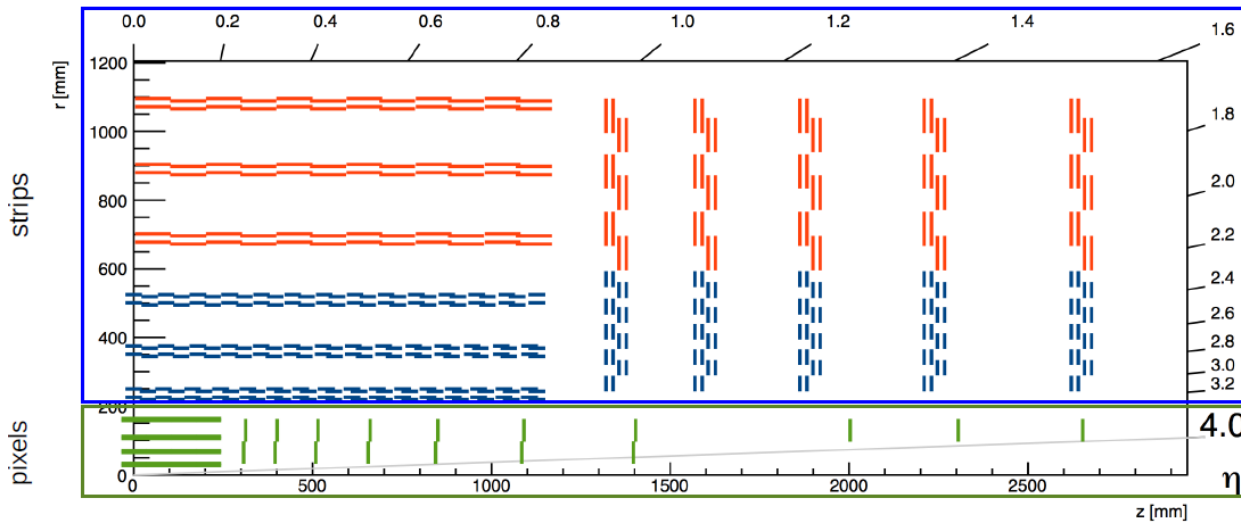
Radiation damage ~ $2 \times 10^{16} n_{eq}/cm^2$

Detector elements and electronics exposed to high radiation dose. Degrades signal & limits life time of detectors.

Mitigation

Completely new tracker with radiation hard sensors and readout chips.

CMS Phase II Pixel Upgrade



Small pitch

- 50x50 or 25x100 μm^2
- 1/6 of current size
- Sensor area 2x2 cm^2

Current Sensor Options:

Thin planar

3D pixels

Inner barrel & endcap layers need to be very rad-hard!

Radius = 29 mm: close to beam.

Innermost barrel layer $\sim 0,2 \text{ m}^2$, ~ 500 sensors.

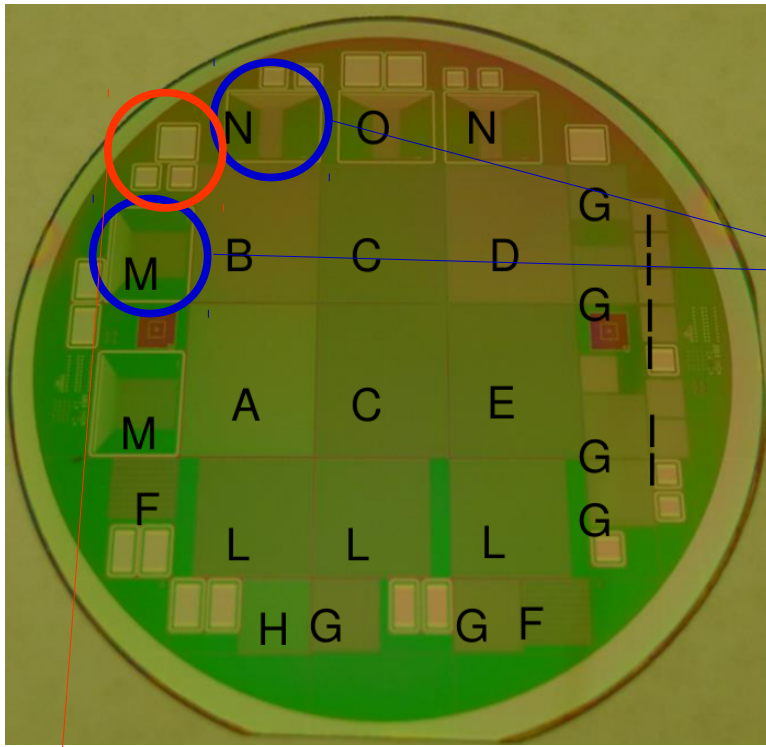
Advantages:

- Electrode distance decoupled from sensitive detector thickness.
 - Lower depletion voltage.
 - Shorter drift distance.
 - ✓ Less trapping, **rad hard**.
- Active or slim edges are a natural feature of 3D technology.

Challenges:

- Complex production process.
- Higher capacitance.
- Non-uniform response in columns and low field regions.

CNM small pitch double sided 3D run (7781)



Previous studies done and presented in the last RD50 workshop:

Strips: $50 \times 50 \times 230 \mu\text{m}^3$ (M).
 $25 \times 100 \times 230 \mu\text{m}^3$ (N).

Completed

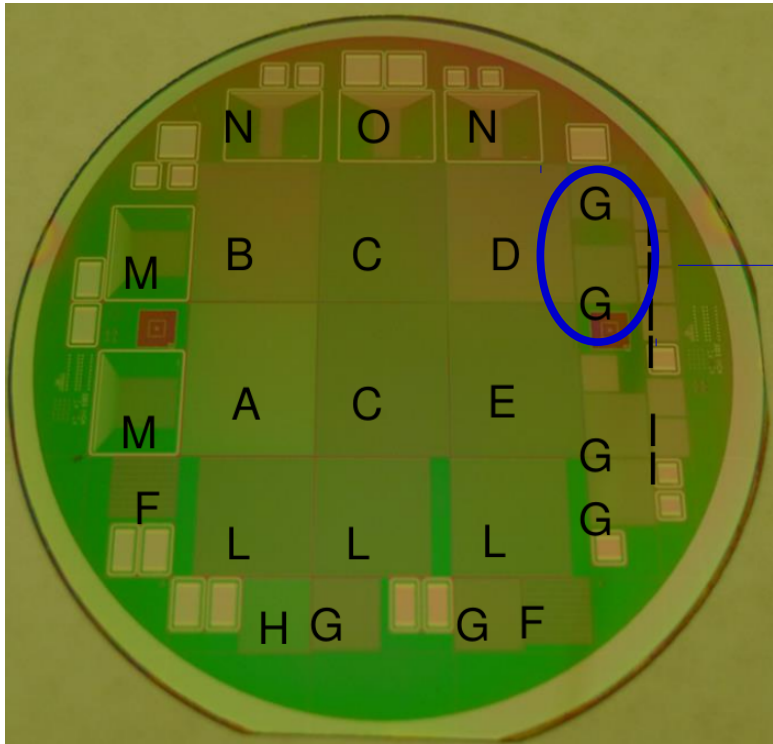
Read out using Alibava.
Irradiated up to $1\text{E}16 \text{ n}_{\text{eq}}/\text{cm}^2$.
Tested in a test beam at CERN (SPS).
Measured with Sr-90 source.
IV/Power studies done.

Pads: $50 \times 50 \times 230 \mu\text{m}^3$.
 $25 \times 50 \times 230 \mu\text{m}^3$.

On going

Irradiation campaign up to $2\text{E}16 \text{ n}_{\text{eq}}/\text{cm}^2$ in three steps.
First step at $5\text{E}15 \text{ n}_{\text{eq}}/\text{cm}^2$ done.
Measurements with Sr-90 source in progress ...
IV/CV characterization and TCT measurements in progress ...

CNM small pitch double sided 3D run (7781)



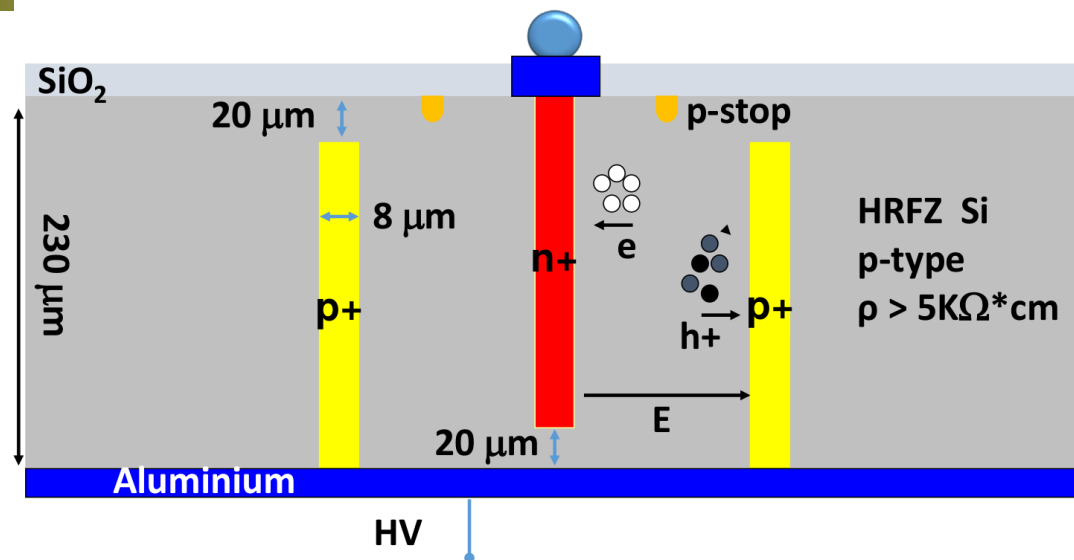
This study focuses on **unirradiated** 3D pixel (G) readout using ROC4sens chip:

→ G: pixel $50 \times 50 \times 230 \mu\text{m}^3$ (1E).

CNM double sided 3D process:

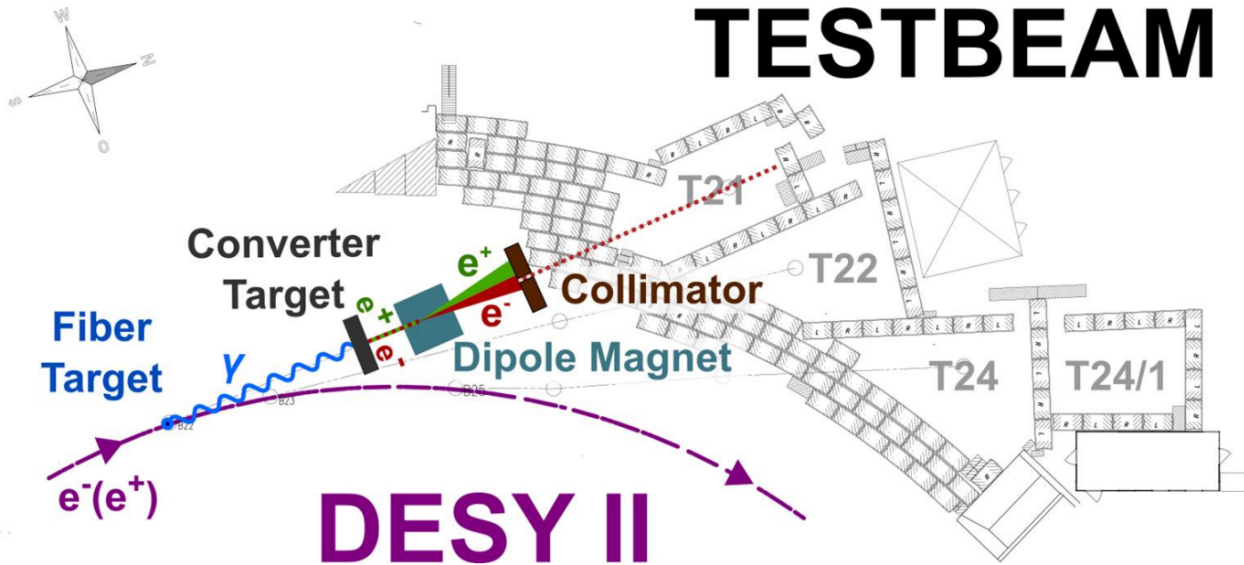
Cross section.

Produced in 2016 within the RD50 collaboration.

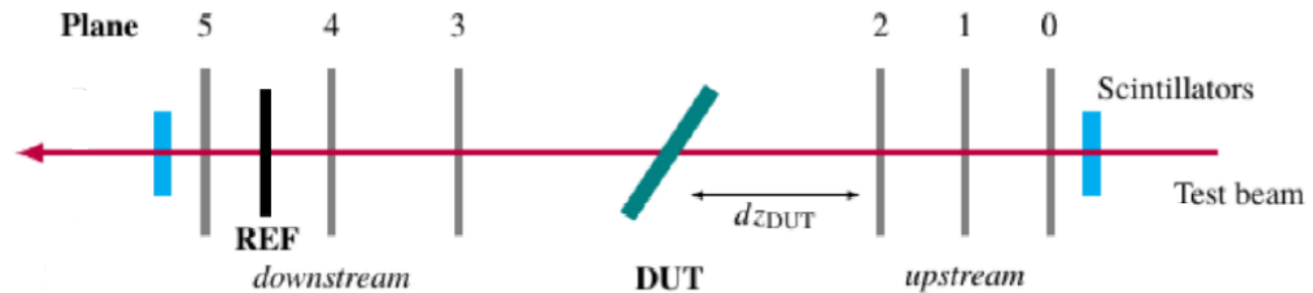


The set-up (T21 area)

November 2017



Electrons at 5.6 GeV



EUDET DATURA telescope for tracking.

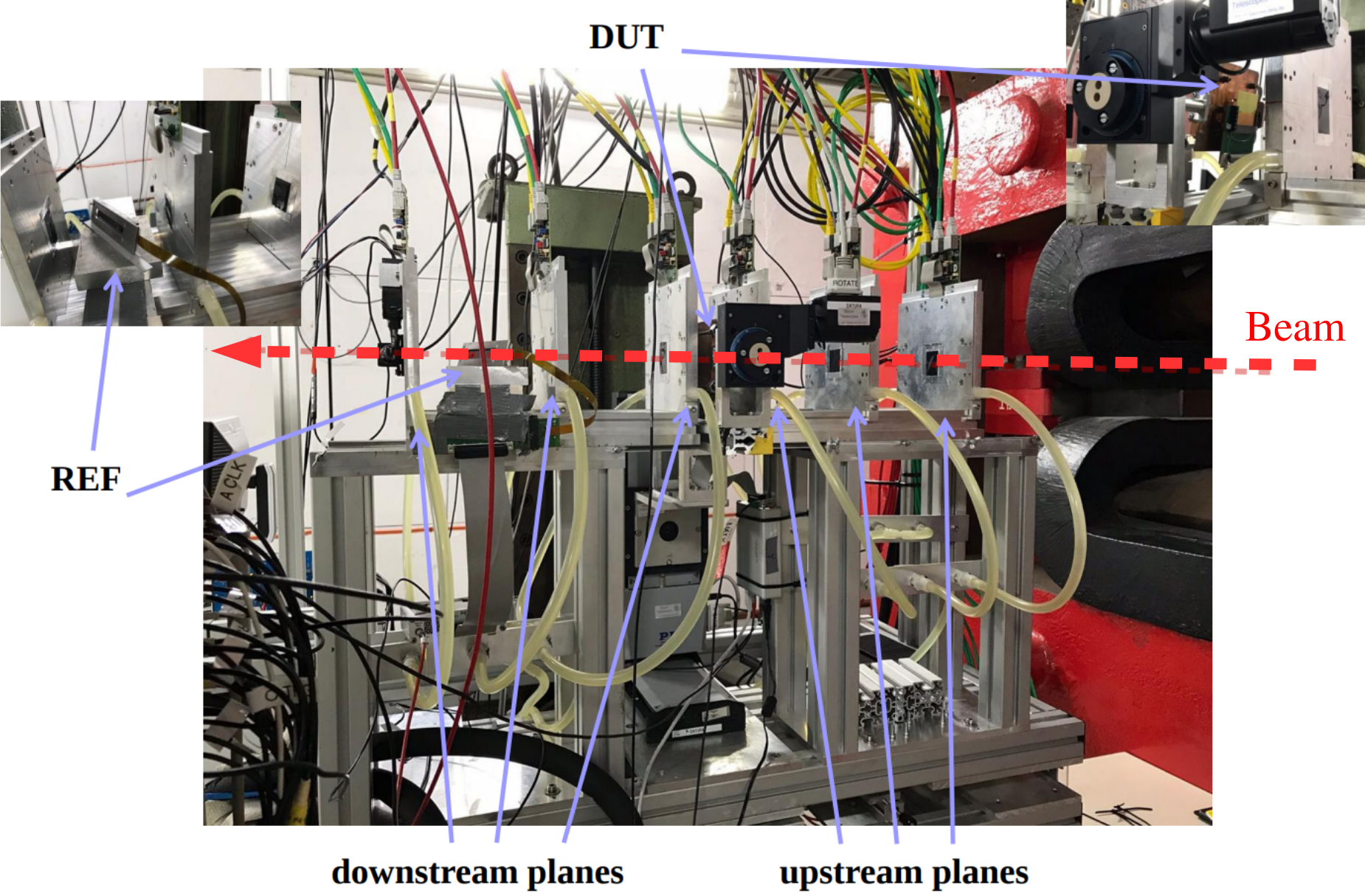
Multiple scattering effect → telescope reconstruction in two legs.

Scintillators for triggering.

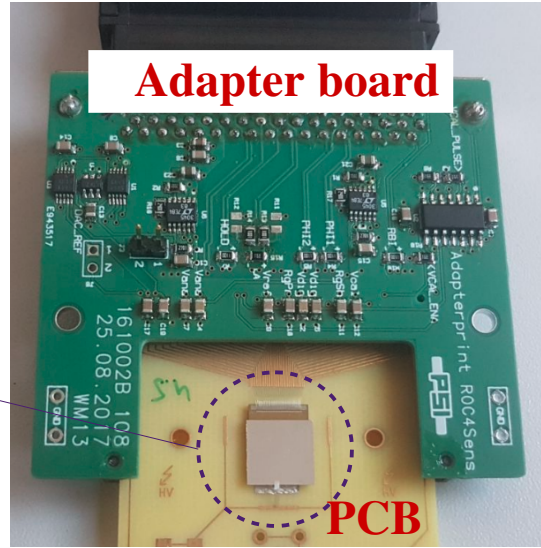
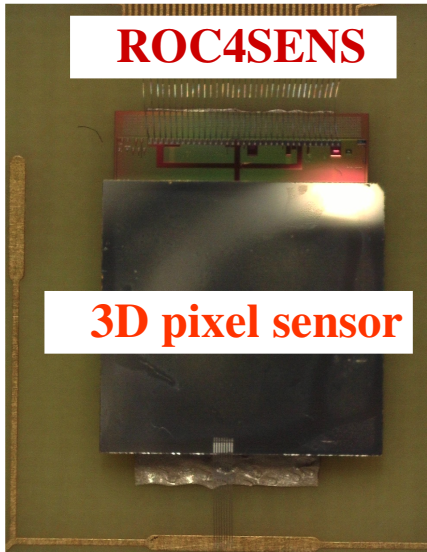
DUT like **REF**erence plane for timing (efficiency measurements).

Device **U**nder **T**est (3D pixel sensor + ROC4sens chip).

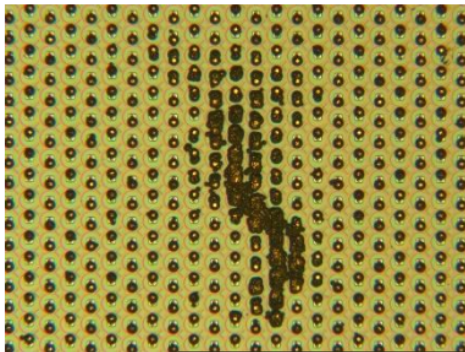
The set-up (Pictures)



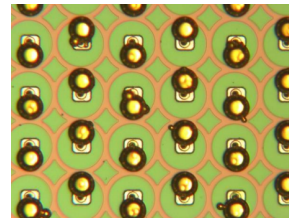
Device Under Test



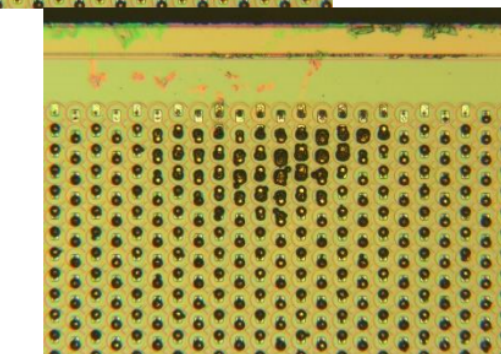
Based on CMS pixel-dtb:
Widely used within CMS.
Limitations in readout speed.



Electroless **Under Bump Metallization** in chips “G” ROC4sens at CNM.



Flip-chipping of ROC4sens on 3D sensors done at IZM.



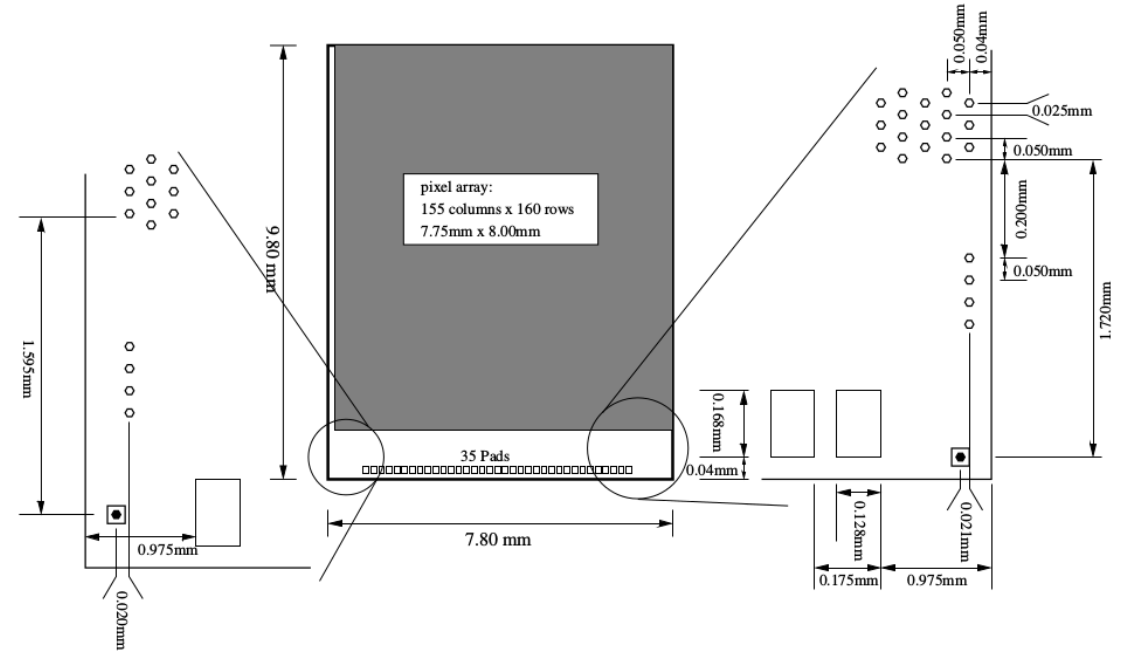
7781-DET-3 G5

CMS R&D ROC: ROC4SENS

More information on Tilman's talk tomorrow → “ROC4SENS -- a generic readout chip for sensor studies”

Size: $9.80 \times 7.80 \text{ mm}^2$.

- $155 \times 160 = 24800$ pixels.
- Bump pads staggered.
- Pattern fits Phase 0 sensors.
- 2×4 bump pads for guard ring connection.
- 35 wire bond pads with pitch $175 \text{ }\mu\text{m}$.
 - 2 power lines, 2 GNDs.
 - 4 reference Voltages.
 - 5 LVDS signals in.
 - 3 digital inputs.
 - 2 LVDS signals out.

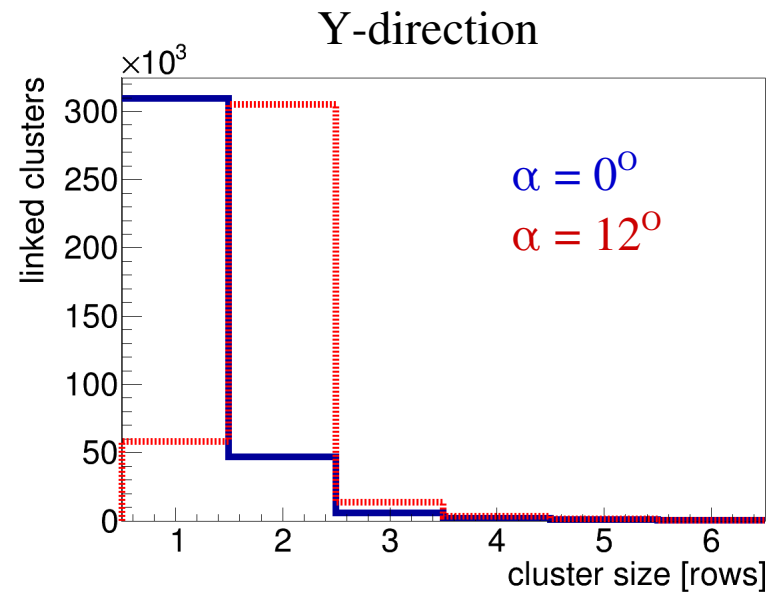
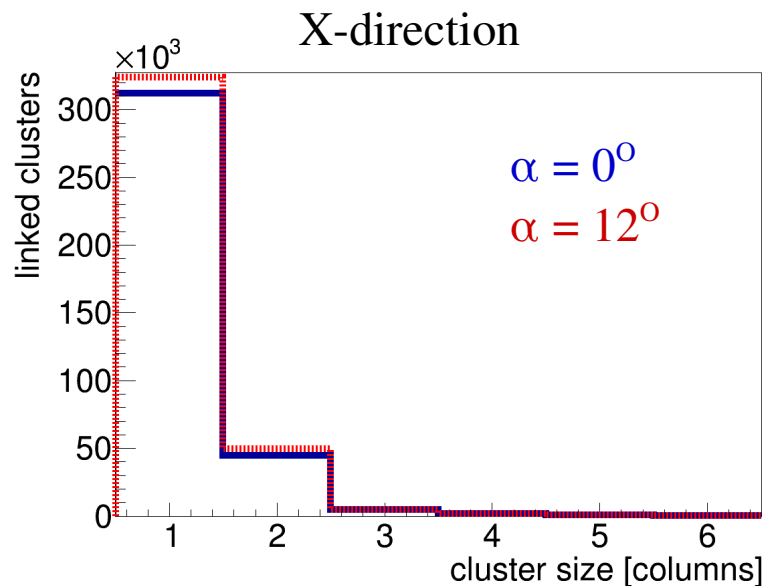
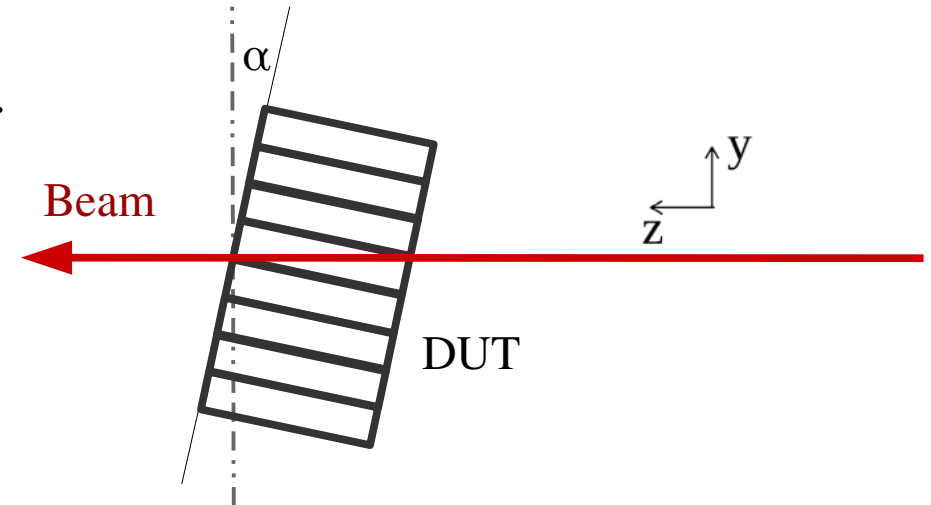


- Analogue signal transmission.
- Simple operation.
- Small pitch for phase II sensor development: $50 \times 50 \text{ }\mu\text{m}^2$.
- Expected to be as radiation hard as the tested sensors.

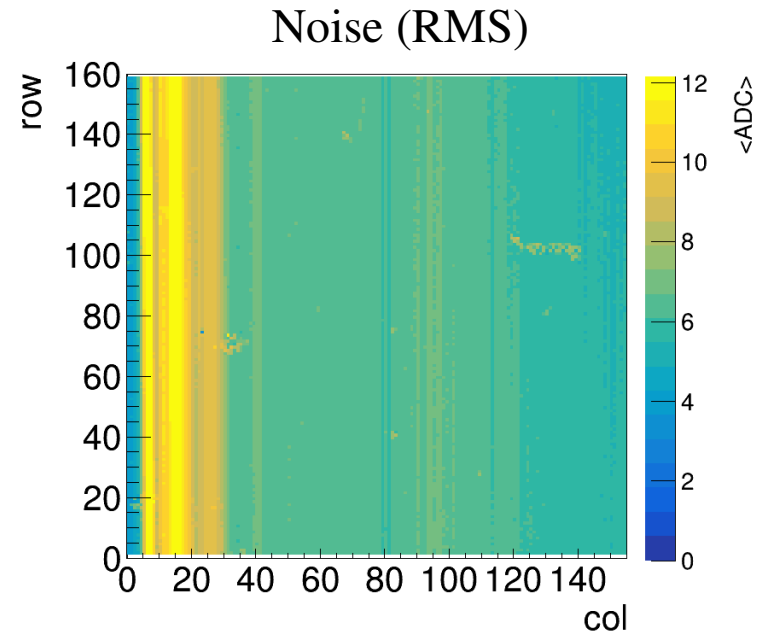
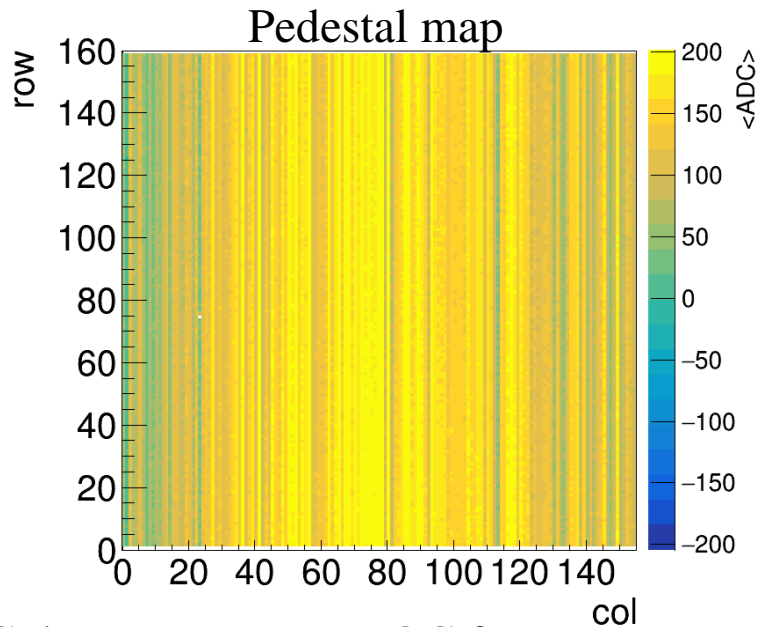
Test beam results

$$\arctan\left(\frac{\text{pitch}}{\text{thickness}}\right) = \arctan\left(\frac{50}{230}\right) = 12.26$$

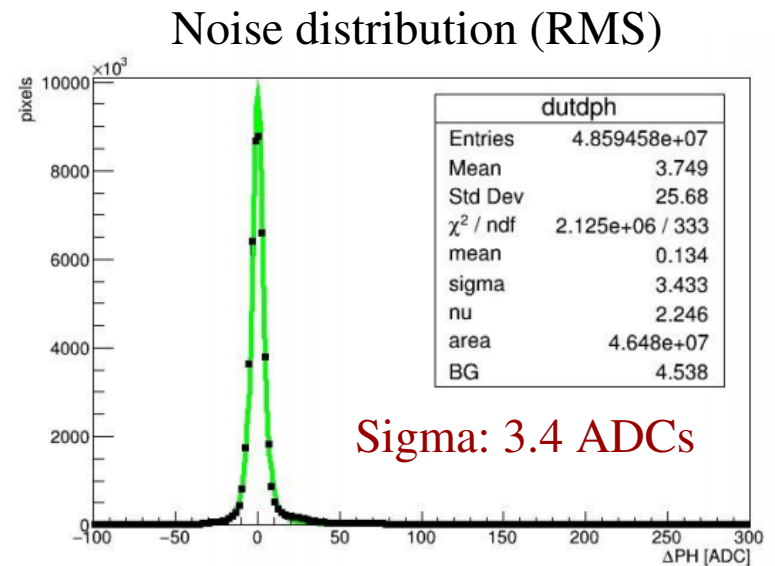
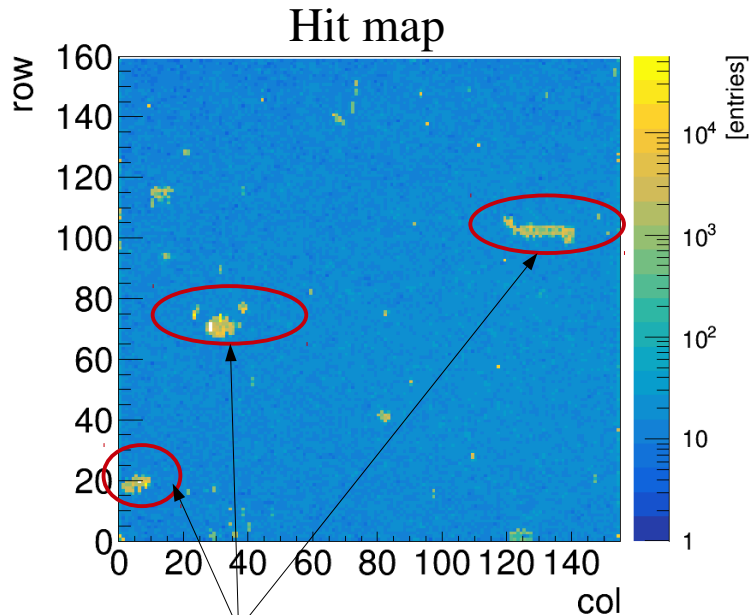
- Available data for two assemblies.
- High statistics at $\alpha = 0^\circ$ (perpendicular incidence) and $\alpha = 12^\circ$ (optimal incidence angle).
Efficiency, charge collection, spatial resolution ...
- Angle scan for one assembly.
DUT resolution vs track incidence angle.
- Room temperature.
- $V_{\text{bias}} = 25$ V (fully depleted above 10 V).



Test beam results

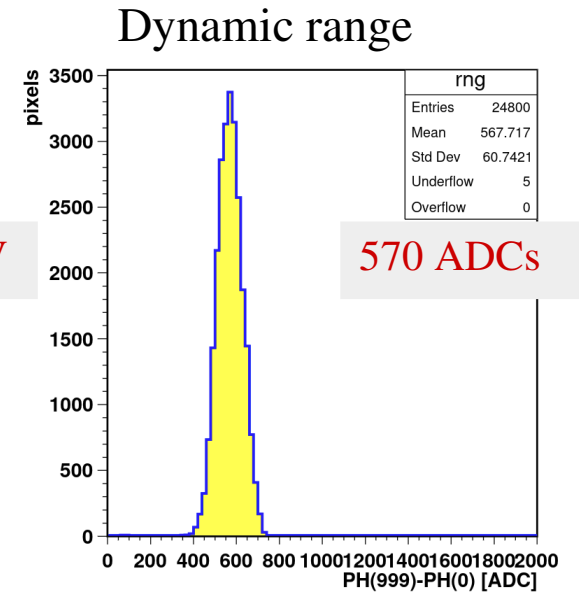
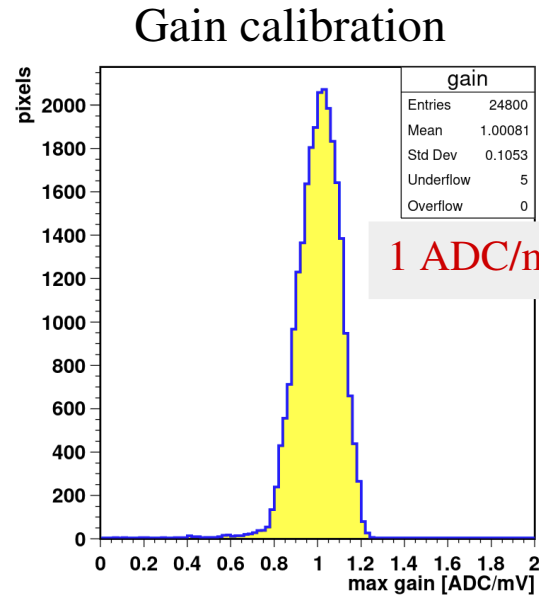
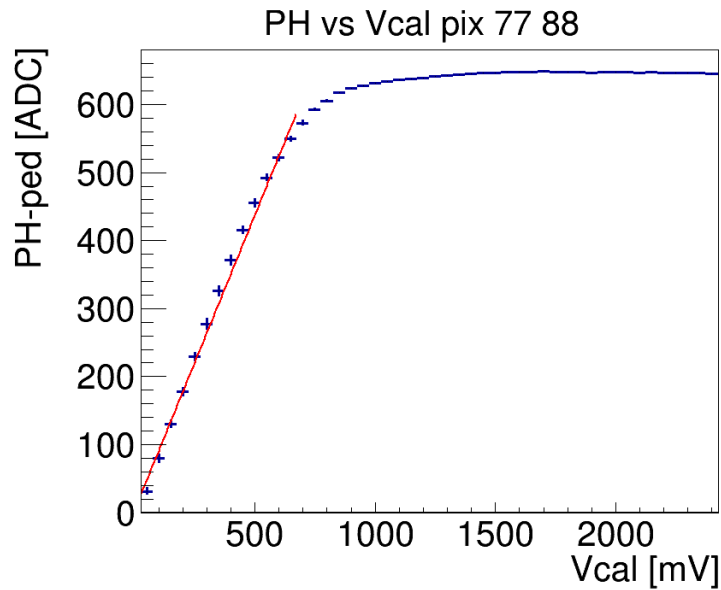


Column pattern → ROC feature: gyrator circuit variation at the end of each column.

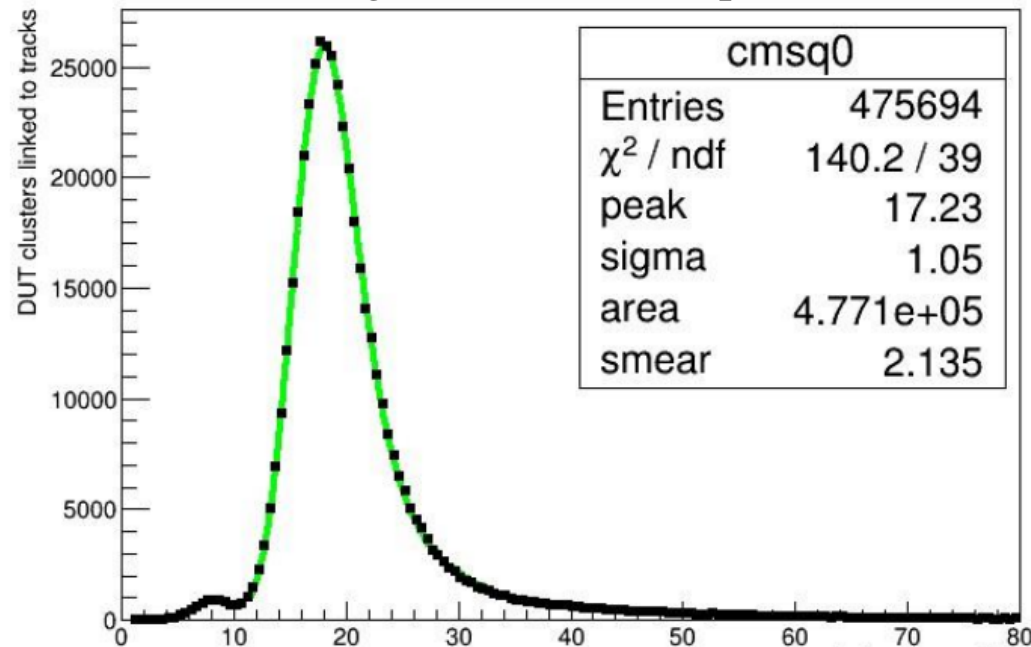


Bad areas on the hit map due to the UBM process.

Test beam results: charge distribution



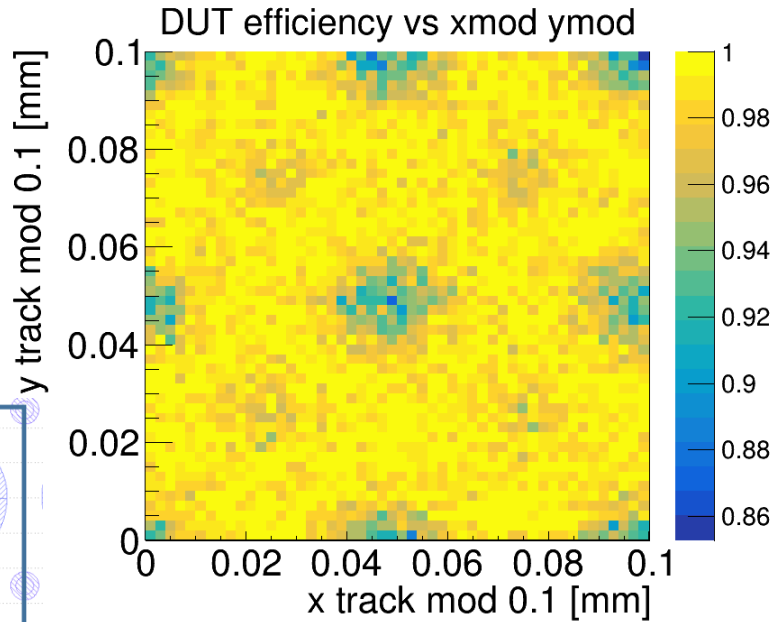
Charge distribution shape



a.u.

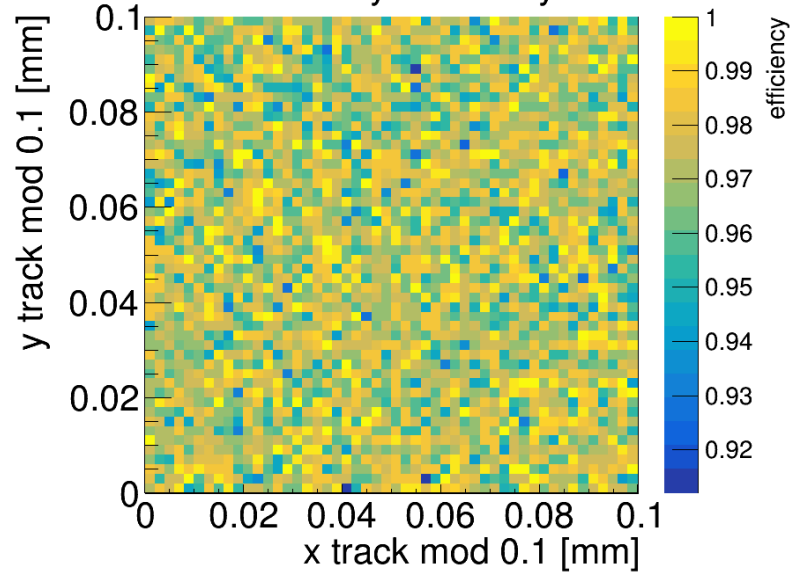
Test beam results: efficiency measurements

Sensor 1



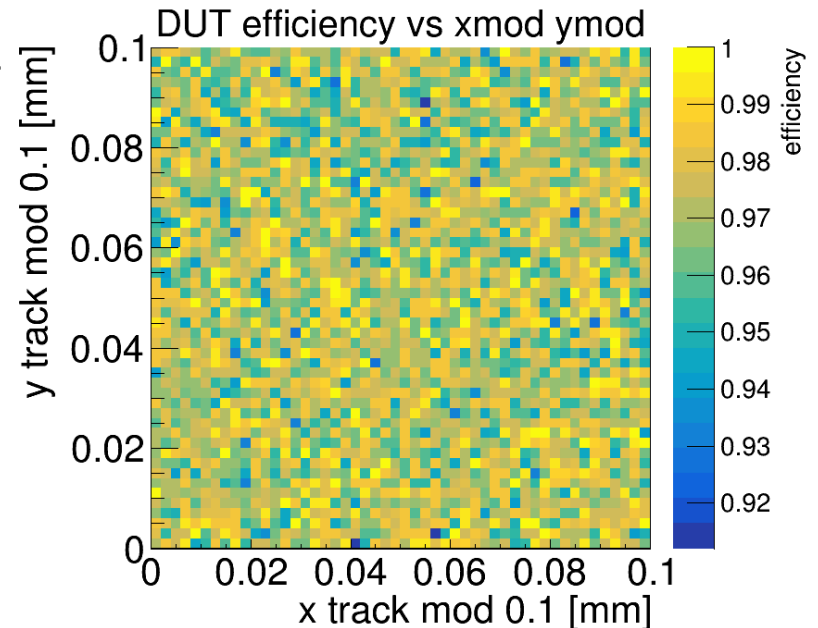
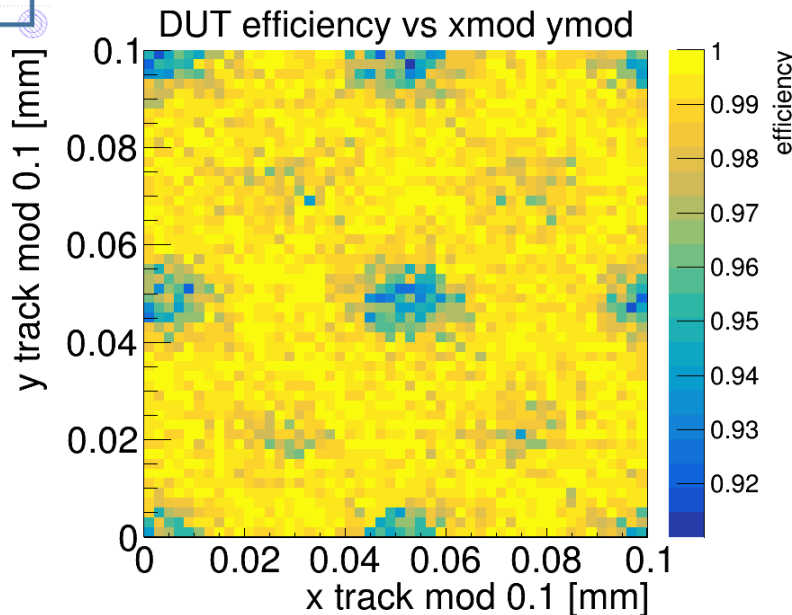
0°

DUT efficiency vs xmod ymod

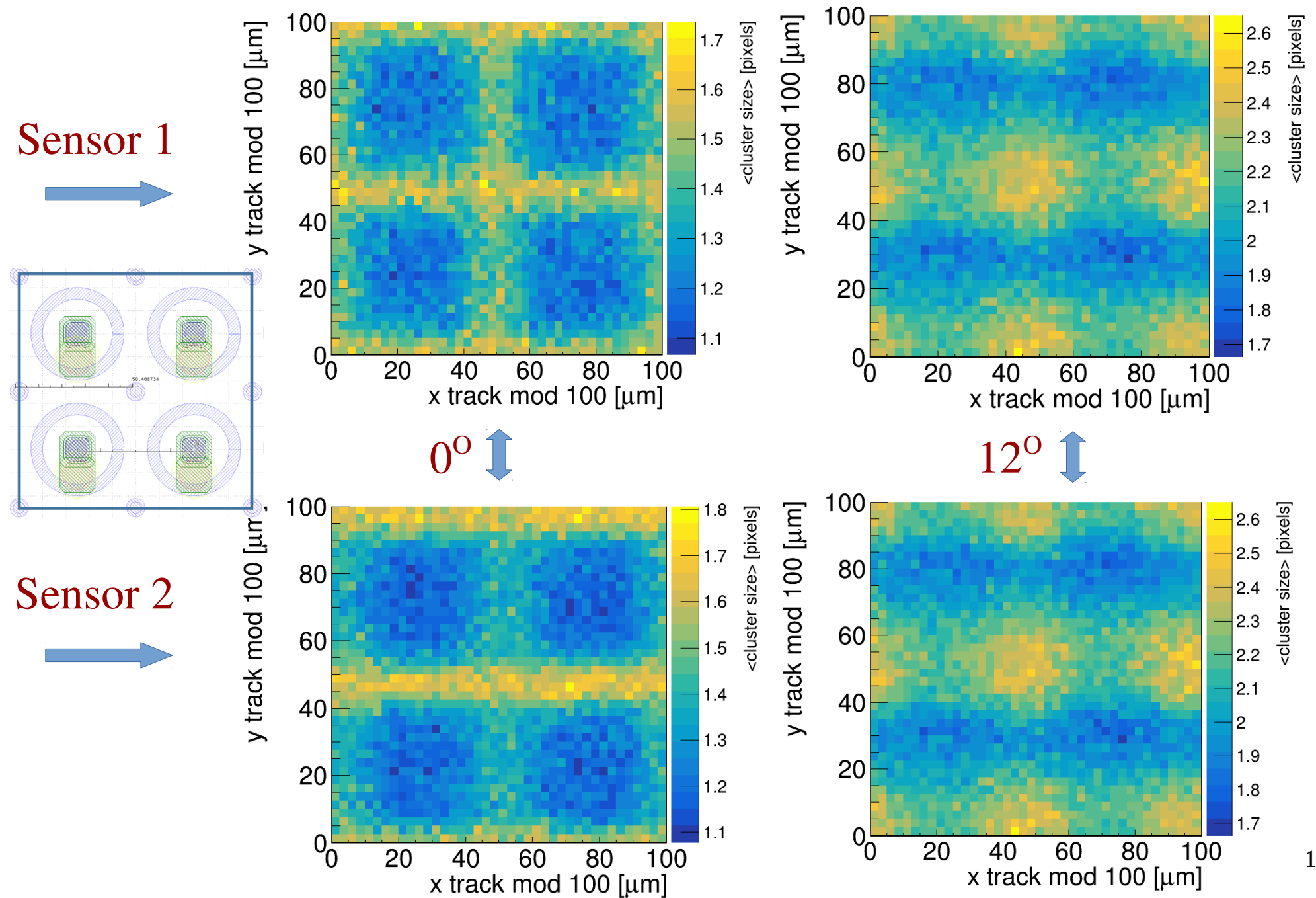


12°

Sensor 2

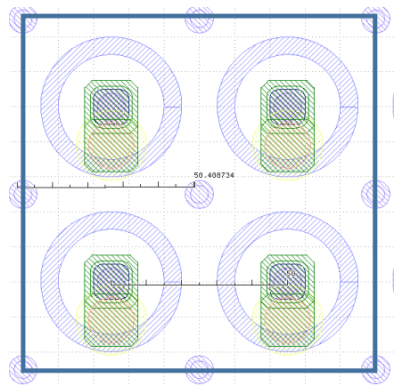


Test beam results: cluster size

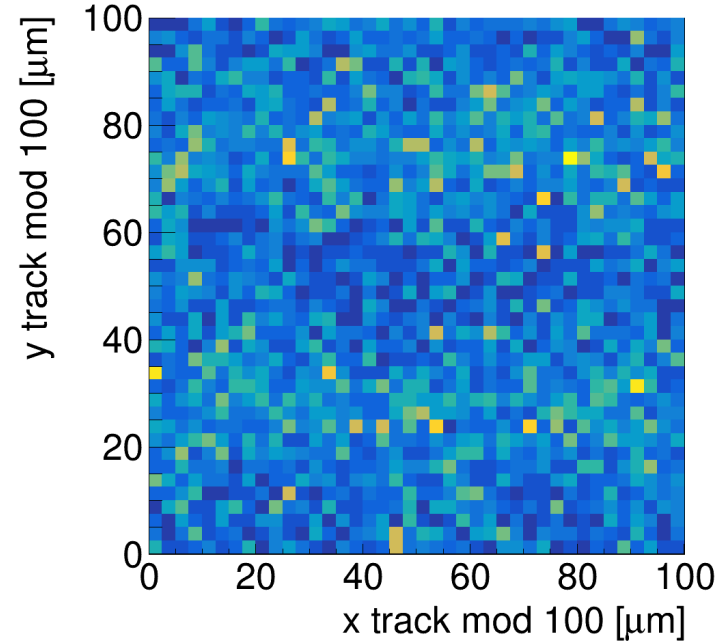
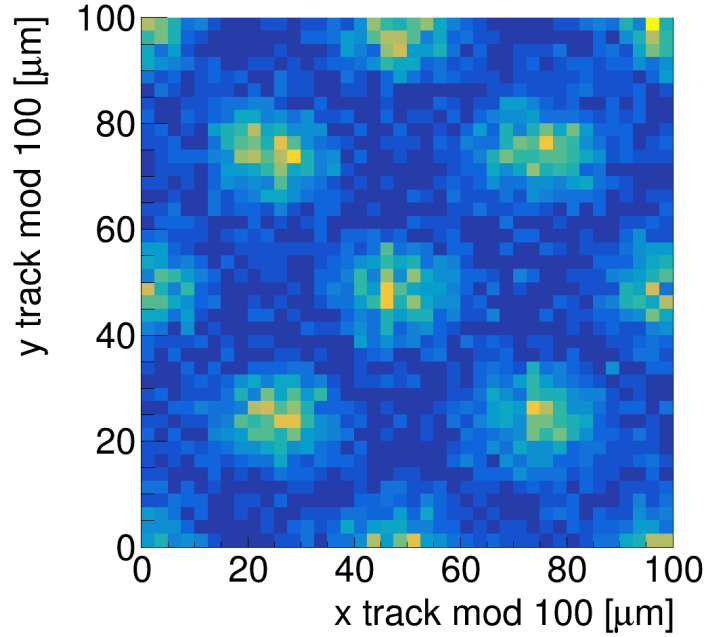


Test beam results: cluster charge (a.u.)

Sensor 1

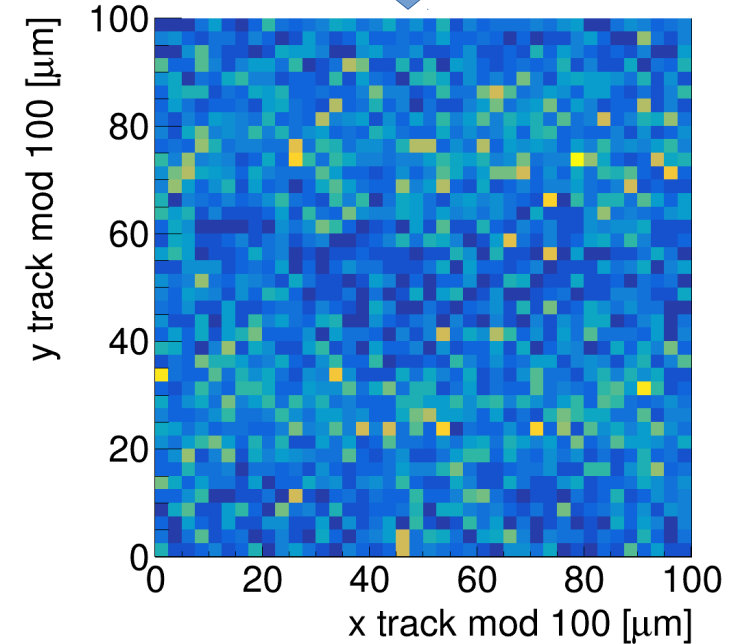
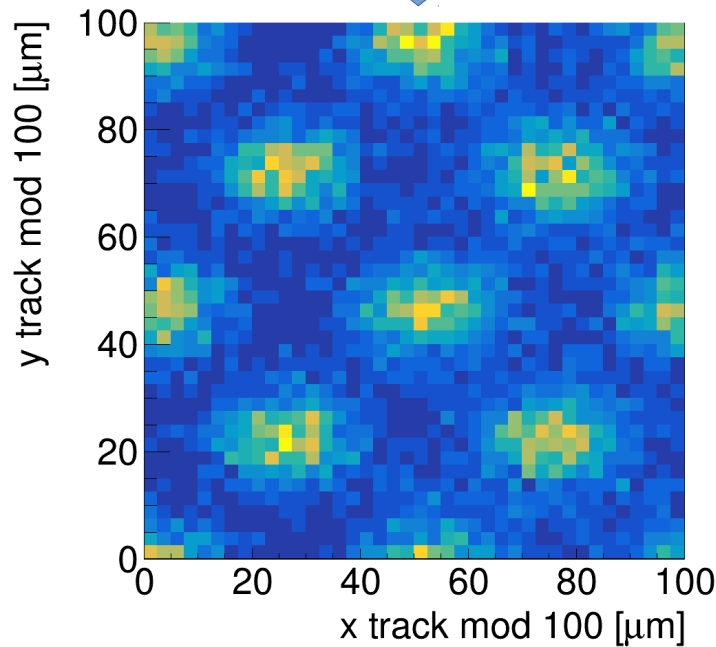


Sensor 2



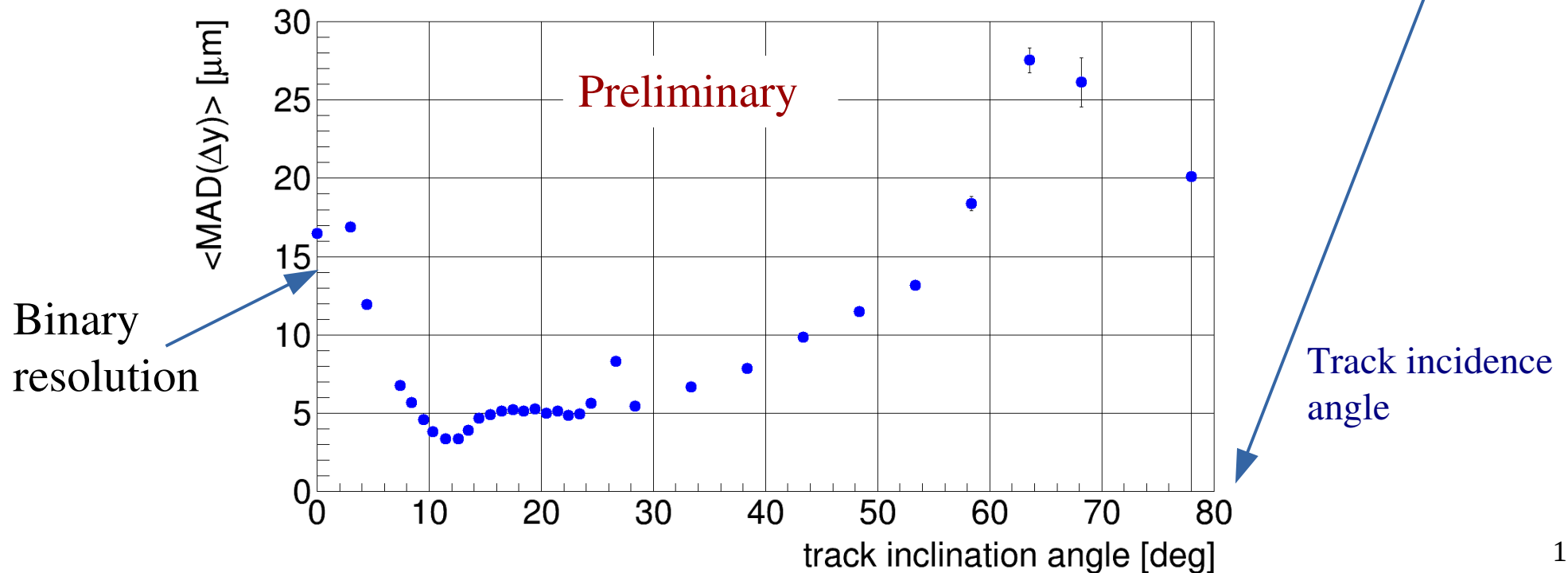
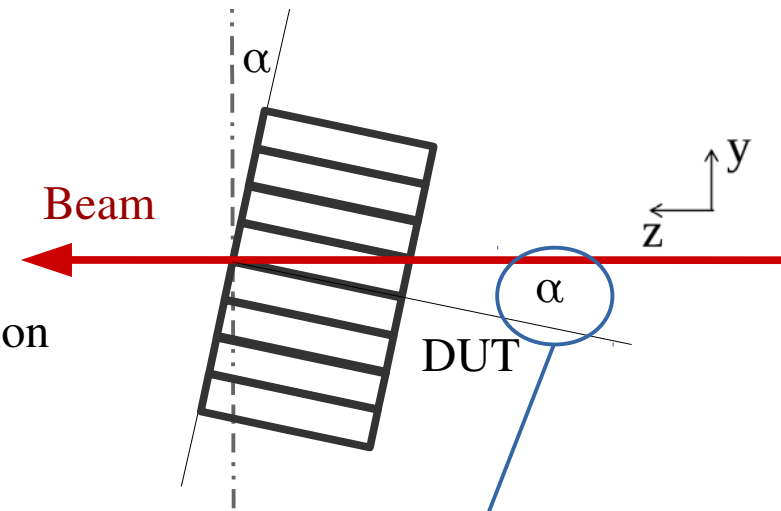
0° 

12° 



Test beam results: spatial resolution vs track incidence angle

- Extrapolation of upstream and downstream tracks to the DUT
- Residuals: cluster position (DUT) – track extrapolation
- DUT spatial resolution:
width of the residual distribution \ominus telescope spatial resolution
- Only clusters within the Landau peak.



Summary and next steps

First results of small pitch unirradiated 3D pixel sensors were presented.

The ROC4sens read-out chip works as expected.

The characterization presented here: spatial resolution, charge collection, efficiency and noise are very promising.

The two assemblies have been already irradiated at $3E15 n_{eq}/cm^2$ and we will try to measure them again this December at DESY test beam.

Acknowledgments

We would like to give our special thanks to Tilman Rohe and Beat Meier (PSI).

